

THC63LVDM83D-Z

24bit COLOR OPEN LDI(LVDS) TRANSMITTER

General Description

The THC63LVDM83D-Z transmitter is designed to support pixel data transmission between Host and Flat Panel Display up to 1080p/WUXGA resolutions.

The THC63LVDM83D-Z converts 28bits of LVCMOS data into four OpenLDI(LVDS) data streams. The transmitter can be programmed for rising edge or falling edge clock through a dedicated pin. At a transmit clock frequency of 160MHz, 24bits of RGB data and 4bits of timing and control data (HSYNC, VSYNC, DE, CONT1) are transmitted at an effective rate of 1120Mbps per OpenLDI(LVDS) channel.

Application

- · Medium and Small Size Panel
- ·Tablet PC / Notebook PC
- · Security Camera / Industrial Camera
- · Multi Function Printer
- · Industrial Equipment
- · Medical Equipment Monitor
- Automotive

Features

- ·Compatible with TIA/EIA-644 LVDS Standard
- ·7:1 OpenLDI(LVDS) Transmitter
- •Operating Temperature Range: -40 to +105°C
- ·No Special Start-up Sequence Required
- Spread Spectrum Clocking Tolerant up to 100kHz Frequency Modulation and +/-2.5% Deviations.
- Wide Dot Clock Range: 8 to 160MHz Suited for TV Signal: NTSC(12.27MHz) - 1080p(148.5MHz) PC Signal: QVGA(8MHz) - WUXGA(154MHz)
- · 56pin TSSOP Package
- •1.2V to 3.3V LVCMOS inputs are supported.
- •LVDS swing is reducible as 200mV by RS-pin to reduce EMI and power consumption.
- •PLL requires no external components.
- · Power Down Mode
- •Input clock triggering edge is selectable by R/F-pin.
- •EU RoHS Compliant

Block Diagram

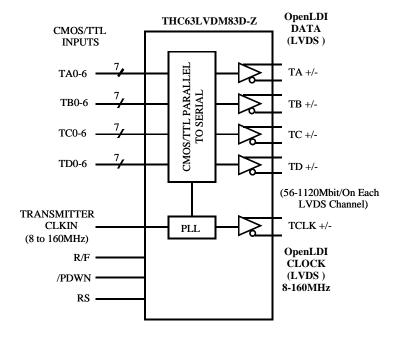


Figure 1. Block Diagram



Pin Diagram

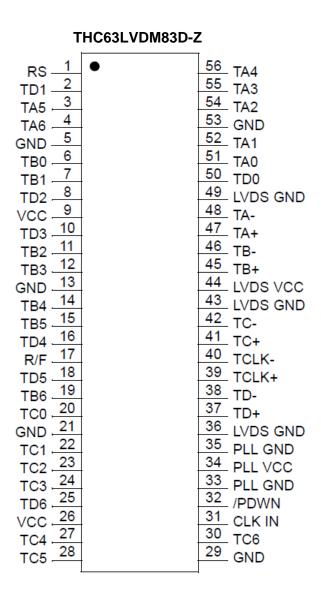


Figure 2. Pin Diagram



Pin Description

Pin Name	Pin #	Direction	Туре	Description			
TA+, TA- TB+, TB-	47, 48 45, 46 41, 42			Open LDI(LVDS) Data Out			
TC+, TC- TD+, TD- TCLK+,	37, 38	Output LVDS					
TCLK-	39, 40			Open LDI(LVDS) Clock Out			
TA0 ~ TA6 TB0 ~ TB6	51, 52, 54, 55, 56, 3, 4 6, 7, 11, 12, 14, 15, 19						
TC0 ~ TC6	20, 22, 23, 24, 27, 28, 30			Pixel Data Input			
TD0 ~ TD6	50, 2, 8, 10, 16, 18, 25			H : Normal Operation			
/PDWN	32			L : Power Down (All outputs are Hi-Z)			
				LVDS Swing Mode, VREF Select See Fig.7			
		Input	LVCMOS	RS LVDS Small Swing			
RS	1		_, _,	Swing Input Support			
K5	I			VCC 350mV N/A			
				0.6V~1.4V 350mV RS=VREF			
				GND~0.2V 200mV N/A			
				VREF : is Input Reference Voltage			
R/F	17			Input Clock Triggering Edge Select H: Rising Edge			
K/F	17			L: Falling Edge			
CLKIN	31			Input Clock			
VCC	9, 26			Power Supply Pins for LVCMOS inputs an digital circuit.			
GND	5, 13, 21, 29, 53	Davisar		Ground Pins for LVCMOS Inputs and Digital Circuitry.			
LVDS VCC	44	Power	-	Power Supply Pins for LVDS Outputs.			
LVDS GND	36, 43 49			Ground Pins for LVDS Outputs.			
PLL VCC	34			Power Supply Pin for PLL Circuitry.			
PLL GND	33, 35			Ground Supply Pin for PLL Circuitry.			

Table 1. Pin Description



Absolute Maximum Ratings

Parameter	Min	Max	Unit
All Supply Voltage (VCC, LVDS_VCC, PLL_VCC)	-0.3	+4.0	V
LVCMOS Input Voltage	-0.3	VCC + 0.3	V
LVDS Output Pin	-0.3	VCC + 0.3	V
Output Current	-30	30	mA
Junction Temperature	-	+125	°C
Storage Temperature	-55	+150	°C
Reflow Peak Temperature	-	+260	°C
Reflow Peak Temperature Time	-	10	sec
Maximum Power Dissipation @+25°C	-	1.8	W

Table 2. Absolute Maximum Ratings

Recommended Operating Conditions

Symbol	Parameter	Min	Тур.	Max	Unit
VCC, LVDS_VCC, PLL_VCC	All Supply Voltage	3.0	3.3	3.6	V
Ta	Operating Ambient Temperature	-40	25	+105	°C
f _{clk}	Clock Frequency	8	-	160	MHz

Table 3. Recommended Operating Conditions

Equivalent LVDS Output Schematic Diagram

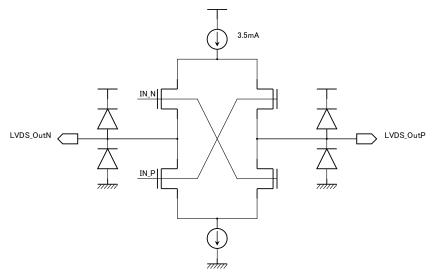


Figure 3. LVDS Output Schematic Diagram

[&]quot;Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the device should be operated at these limits. The tables of "Electrical Characteristics Table 4, 5, 6, 7" specify conditions for device operation. "Absolute Maximum Rating" value also includes behavior of overshooting and undershooting.



Power Consumption

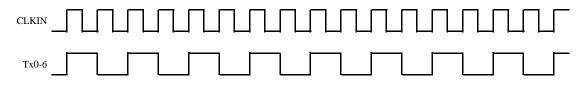
Over recommended operating supply and temperature range unless otherwise specified

Symbol	Parameter		Conditions		Тур.*	Max	Unit
		RL=100Ω, CL	.=5pF, f=85M	Hz, RS=VCC	48	67	mA
		RL=100Ω, RS=VCC	CL=5pF,	f=135MHz,	65	83	mA
I _{TCCW}	LVDS Transmitter Operating Current	RL=100Ω, RS=VCC	CL=5pF,	f=160MHz,	73	92	mA
TICCW	Worst Case Pattern (Fig.4)	RL=100Ω, CL=5pF, f=85MHz, RS=GND			40	56	mA
	(r ig.+)	RL=100Ω, RS=GND	CL=5pF,	f=135MHz,	56	71	mA
		RL=100Ω, RS=GND	CL=5pF,	f=160MHz,	65	80	mA
I _{TCCS}	LVDS Transmitter Power Down Current	/PDWN=L, All	Inputs=L or I	Н	-	10	μΑ

^{*}Typ. values are at the conditions of VCC=3.3V and Ta = +25°C

Table 4. Power Consumption

Worst Case Pattern



x=A,B,C,D

Figure 4. Worst Case Pattern



Electrical Characteristics

LVCMOS DC Specifications

Over recommended operating supply and temperature range unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ.*	Max	Unit
V_{IH}	High Level Input Voltage	RS=VCC or GND	2.0	-	VCC	V
V_{IL}	Low Level Input Voltage	RS=VCC or GND	GND	-	8.0	V
$V_{\rm DDQ}^{1}$	Small Swing Voltage	-	1.2	-	2.8	V
V_{REF}	Input Reference Voltage	Small Swing (RS=V _{DDQ} /2)	-	$V_{DDQ}/2$	-	
V _{SH} ²	Small Swing High Level Input Voltage	$V_{REF=} V_{DDQ}/2$	V _{DDQ} /2 +150m V	-	-	V
V _{SL} ²	Small Swing Low Level Input Voltage	V _{REF=} V _{DDQ} /2	-	-	V _{DDQ} /2 -150mV	V
I _{INC}	Input Current	$GND \leq V_{IN} \leq VCC$	-	-	±10	μΑ

^{*}Typ. values are at the conditions of VCC=3.3V and Ta = +25°C

Notes: $^{1}V_{DDQ}$ voltage defines the max voltage of small swing inputs at RS=VREF. It is not an actual input voltage.

Table 5. LV-CMOS DC Specifications

LVDS Transmitter DC Specifications

Over recommended operating supply and temperature range unless otherwise specified

Symbol	Parameter		nditions	Min	Typ.*	Max	Unit
VOD	Differential Output Valtere	DI =1000	Normal swing RS=VCC Ta=25°C	250	350	450	mV
VOD	Differential Output Voltage	RL=100Ω	Reduced swing RS=GND	110	200	300	mV
ΔVOD	Change in VOD between complementary output states	RL	_=100Ω	-	1	35	mV
VOC	Common Mode Voltage		Ω, Ta=25°C, S=VCC	1.125	1.25	1.375	٧
ΔVOC	Change in VOC between complementary output states	RL	_=100Ω	-	1	35	mV
I _{os}	Output Short Circuit Current	V _{OUT} =GN	ND, RL=100Ω	-	-	-24	mA
I _{OZ}	Output TRI-STATE Current		VN=GND, SND to VCC	-	-	±10	μΑ

^{*}Typ. values are at the conditions of VCC=3.3V and Ta = +25°C

Table 6. LVDS Transmitter DC Specifications

² Small swing signals are applied to TA0-6, TB0-6, TC0-6, TD0-6 and CLKIN.



LVCMOS & LVDS Transmitter AC Specifications

Over recommended operating supply and temperature range unless otherwise specified

Symbol	Parameter	Min	Тур.	Max	Unit
t _{TCIT}	CLK IN Transition Time	-	-	5.0	ns
t _{TCP}	CLK IN Period	6.25	T	125	ns
t _{TCH}	CLK IN High Time	0.35T	0.5T	0.65T	ns
t _{TCL}	CLK IN Low Time	0.35T	0.5T	0.65T	ns
t _{TCD}	CLK IN to TCLK+/- Delay	3T	ı	3T+4	ns
t _{TS}	LVCMOS Data Setup to CLK IN	2.0	ı	-	ns
t _{TH}	LVCMOS Data Hold from CLK IN	0.0	ı	-	ns
t_LVT	LVDS Transition Time	-	0.6	1.5	ns
	Output Skew Accuracy(T=11.76ns)	-	120	275	ps
+ .	Output Skew Accuracy(T=11.76ns)		120	250	ne
t _{sk}	(3.2V≤VCC≤3.6V)	-	120	250	ps
	Output Skew Accuracy(T=7.4ns)	-	120	250	ps
t _{Top1}	Output Data Position0 (T=6.25ns ~ 20ns)	- t _{sk}	0.0	+ t _{sk}	ns
t _{Top0}	Output Data Position1 (T=6.25ns ~ 20ns)	T/7- t _{sk}	T/7	T/7+ t _{sk}	ns
t _{Top6}	Output Data Position2 (T=6.25ns ~ 20ns)	2T/7- t _{sk}	2T/7	2T/7+ t _{sk}	ns
t _{Top5}	Output Data Position3 (T=6.25ns ~ 20ns)	3T/7- t _{sk}	3T/7	3T/7+ t _{sk}	ns
t _{Top4}	Output Data Position4 (T=6.25ns ~ 20ns)	4T/7- t _{sk}	4T/7	4T/7+ t _{sk}	ns
t _{Top3}	Output Data Position5 (T=6.25ns ~ 20ns)	5T/7- t _{sk}	5T/7	5T/7+ t _{sk}	ns
t _{Top2}	Output Data Position6 (T=6.25ns ~ 20ns)	6T/7- t _{sk}	6T/7	6T/7+ t _{sk}	ns
t _{TPLL}	Phase Lock Loop Set	-	-	1.0	ms

^{*}Typ. values are at the conditions of VCC=3.3V and Ta = +25°C

Table 7. LVCMOS & LVDS Transmitter AC Specifications

LVCMOS Input

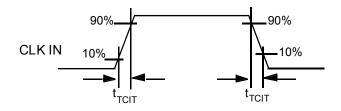


Figure 5. CLKIN Transmission Time

OpenLDI(LVDS) Output

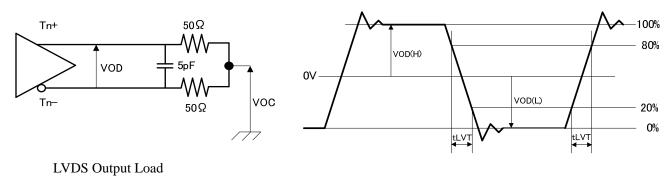
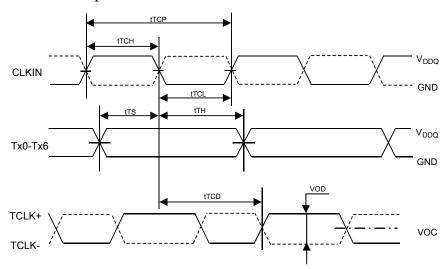


Figure 6. LVDS Output Load and Transmission Time



AC Timing Diagrams

LVCMOS Inputs



RS	VOD
VCC	350mV
0.6V ~ 1.4V	330III V
GND ~ 0.2V	200mV

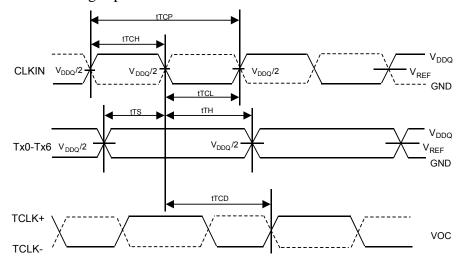
Note:

CLKIN: Solid line denotes the setting of R/F=GND

Dashed line denotes the setting of R/F = VCC

Figure 7. LVCOMS Inputs and LVDS Clock Output Timing 1

Small Swing Inputs



RS	VREF
VCC	
0.6V ~ 1.4V	VDDQ/2
GND ~ 0.2V	

Note:

CLKIN : Solid line denotes the setting of R/F=GND Dashed line denotes the setting of R/F = VCC

Figure 8. LVCMOS Inputs and LVDS Output Timing 2



OpenLDI(LVDS) Output Data Position

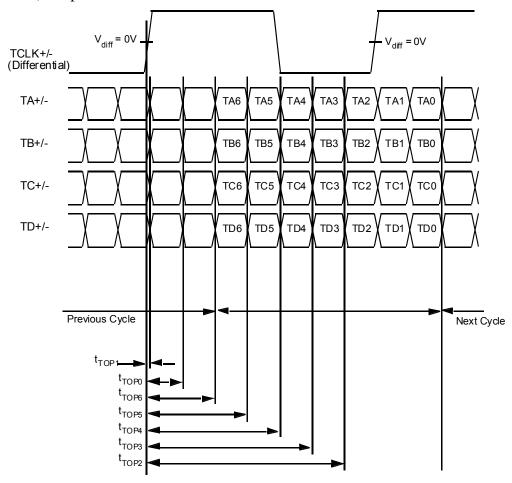


Figure 9. LVDS Output Data Position

Phase Lock Loop Set Time

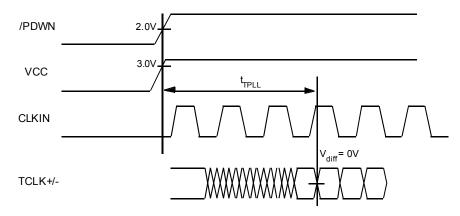


Figure 10. PLL Lock Loop Set Time



Spread Spectrum Clocking Tolerant

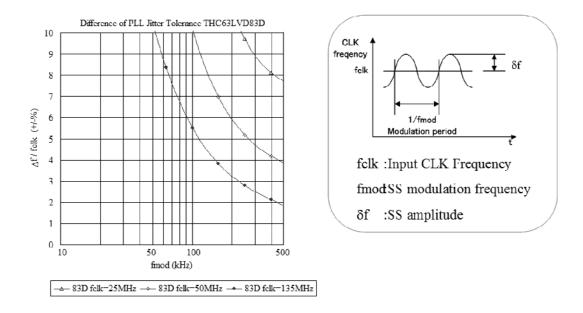


Figure 11. Spread Spectrum Clocking Tolerant

The graph indicates the range that the IC works normally under SS clock input operation. The results are measured with a typical sample on condition of +25C° and 3.3V, therefore these values are for reference and do not guarantee the performance of a product under other circumstance.



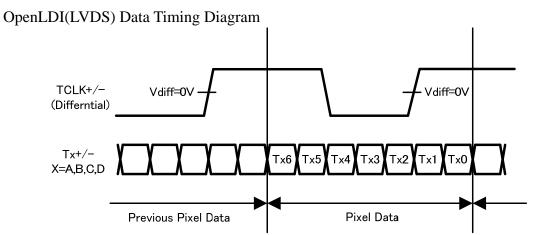


Figure 12. LVDS Data Timing Diagram

THC63LVDM83D-Z Pixel Data Mapping for JEIDA Format (6bit, 8bit Application)

	6bit	8bit
TA0	R2	R2
TA1	R3	R3
TA2	R4	R4
TA1 TA2 TA3	R5	R5
TA4	R6	R6
TA5	R7	R7
TA6	G2	R7 G2
TB0	G3	G3
TB1	G4	G4
TB2	G5	G5
TB3	G6	G6
TB4	G7	G7
TB5	B2	B2
TB6	B3	В3
TC0	B4	B4
TC1	B5	B5
TC2	B6	B6
TC3	B7	B7
TC1 TC2 TC3 TC4	Hsync	Hsync
TC5	Vsync	Vsync
TC6	DE	DE
TD0	-	Vsync DE R0
TC6 TD0 TD1 TD2 TD3 TD4 TD5	-	R1
TD2	-	G0
TD3	-	G1
TD4	-	В0
	-	B1
TD6	-	N/A

Note: Use TA to TC channels and open TD channel for 6bit application.

Table 8. Data Mapping for JEIDA Format



THC63LVDM83D-Z Pixel Data Mapping for VESA Format (6bit, 8bit Application)

	6bit	8bit
TA0	R0	R0
TA1	R1	R1
TA2	R2	R2
TA3	R3	R3
TA4	R4	R4
TA5	R5	R5
TA6	G0	G0
TB0 TB1	G1	G0 G1
TB1	G2	G2
TB2	G3	G3
TB2 TB3 TB4 TB5	G4	G4
TB4	G5	G5
TB5	B0	B0
TB6	B1	B1
TC0	B2	B2
TC1	В3	B3
TC2	B4	B4
TC3	B5	B5
TC4	Hsync	Hsync
TC5	Vsync	Vsync DE
TC6	DE	DE
TD0	-	R6
TD1	-	R7
TD2	-	G6
TC0 TC1 TC2 TC3 TC4 TC5 TC6 TD0 TD1 TD2 TD3 TD4 TD5 TD6	-	G7
TD4	-	B6
TD5	-	B7
TD6	-	N/A

Note: Use TA to TC channels and open TD channel for 6bit application.

Table 9. Data Mapping for VESA Format



Normal Connection

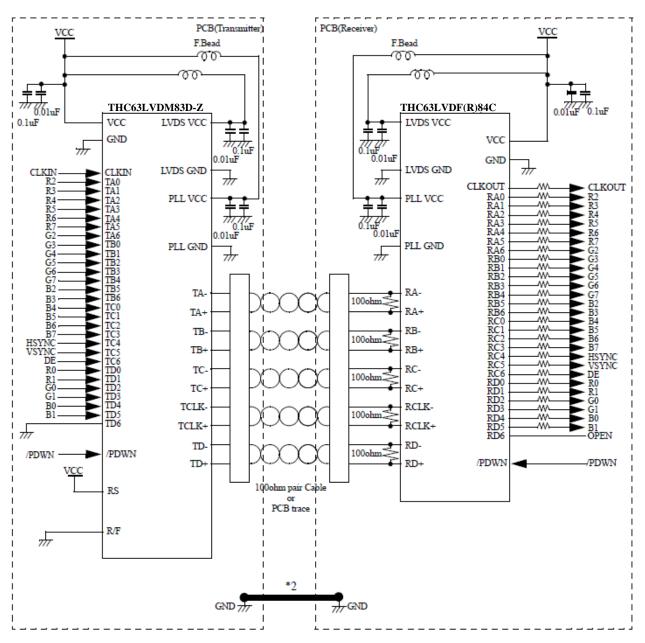


Figure 13. Typical Connection Diagram



Notes

1) Cable Connection and Disconnection

Do not connect and disconnect the OpenLDI(LVDS) cable, when the power is supplied to the system.

2) GND Connection

Connect each GND of the PCB which THC63LVDM83D-Z and OpenLDI(LVDS)-Rx on it. It is better for EMI reduction to place GND cable as close to OpenLDI(LVDS) cable as possible.

3) Multi Drop Connection

Multi drop connection is not recommended.

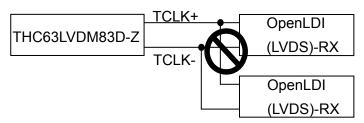
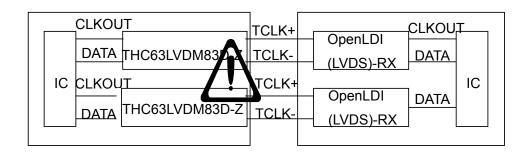


Figure 14. Multi Drop Connection

4) Asynchronous use

Asynchronous using such as following systems is not recommended.



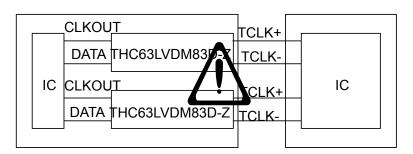
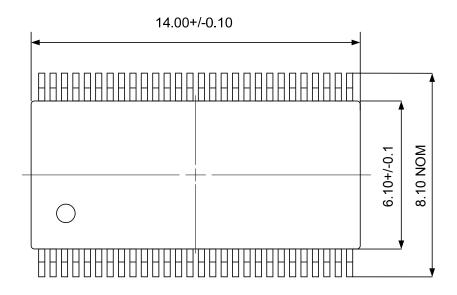
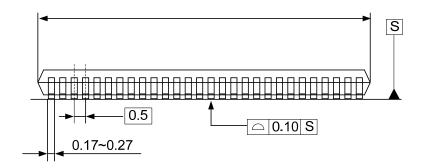


Figure 15. Asynchronous Use



Package





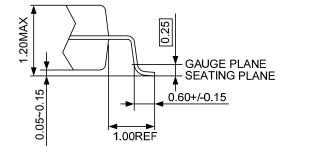


Figure 16. Package Diagram

UNIT:mm



Reference Land Pattern

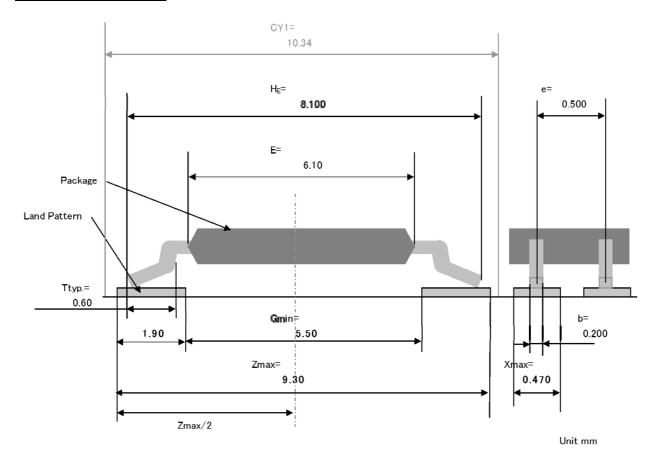


Figure 17. Reference of Land Pattern

The recommendation mounting method of THine device is reflow soldering. The reference pattern is using the calculation result on condition of reflow soldering.

Notes

This land pattern design is a calculated value based on JEITA ET-7501.

Please take into consideration in an actual substrate design about enough the ease of mounting, the intensity of connection, the density of mounting, and the solder paste used, etc... The optimal land pattern size changes with these parameters. Please use the value shown by the land pattern as reference data.



Notices and Requests

- 1. The product specifications described in this material are subject to change without prior notice.
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5. Product Application

- 5.1 Application of this product is intended for and limited to the following applications: audio-video device, office automation device, communication device, consumer electronics, smartphone, feature phone, and amusement machine device. This product must not be used for applications that require extremely high-reliability/safety such as aerospace device, traffic device, transportation device, nuclear power control device, combustion chamber device, medical device related to critical care, or any kind of safety device.
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- 9. Customers are asked, if required, to judge by themselves if this product falls under the category of strategic goods under the Foreign Exchange and Foreign Trade Control Law.
- 10. The product or peripheral parts may be damaged by a surge in voltage over the absolute maximum ratings or malfunction, if pins of the product are shorted by such as foreign substance. The damages may cause a smoking and ignition. Therefore, you are encouraged to implement safety measures by adding protection devices, such as fuses.

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MAX96708GTJ/V+ MAX9217ECM/V+ MAX9218ECM+T